

# SGM25661 3.5V, 6A, Ultra-Low On-Resistance Load Switch

#### **GENERAL DESCRIPTION**

The SGM25661 is an ultra-low on-resistance, integrated N-MOSFET, single-channel load switch. The device operates over a wide input voltage range of 0.6V to 3.5V, and is controlled by the ON pin which is capable of interfacing directly with low-voltage control signals.

The device can provide a 6A maximum continuous load current. Ultra-low on-resistance and high current capability make this product ideal for driving processor rails with tight voltage dropout tolerances. The fast rise time allows the power rails to rise quickly when the switch is enabled, thus reducing the distribution response time.

The SGM25661 offers the fast output discharge function in disable status.

The SGM25661 is available in a Green TDFN-3×3-8EL package.

#### **FEATURES**

- Input Voltage Range: 0.6V to 3.5V
- V<sub>BIAS</sub> Voltage Range: 3V to 5.5V
- Ultra-Low On-Resistance:

 $R_{ON} = 5.3 m\Omega$  (TYP) at  $V_{IN} = 2.5 V$ ,  $V_{BIAS} = 5 V$ 

- Maximum Continuous Load Current: 6A
- Low Quiescent Current: 0.6µA (TYP)
- Support with 1.2V, 1.8V, 2.5V and 3.3V GPIOs
- Rise Time: 8.1µs at V<sub>IN</sub> = 2.5V, V<sub>BIAS</sub> = 5V
- Fast Output Discharge
- -40°C to +85°C Operating Temperature Range
- Available in a Green TDFN-3×3-8EL Package

#### **APPLICATIONS**

Ultrabook

Notebook

**Tablet Computer** 

Servers

Set-Top Boxes

Telecom Systems

#### TYPICAL APPLICATION

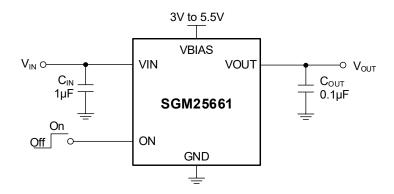


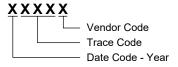
Figure 1. Typical Application Circuit

#### PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM25661	TDFN-3×3-8EL	-40°C to +85°C	SGM25661YTGB8G/TR	SGM GJPGB XXXXX	Tape and Reel, 4000

#### MARKING INFORMATION

NOTE: XXXXX = Date Code, Trace Code and Vendor Code.



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

#### ABSOLUTE MAXIMUM RATINGS

	_
Input Voltage, V <sub>IN</sub>	0.3V to 4V
Bias Voltage, V <sub>BIAS</sub>	0.3V to 6V
Output Voltage, V <sub>OUT</sub>	0.3V to 4V
ON Pin Voltage, V <sub>ON</sub>	0.3V to 6V
Maximum Continuous Load Current	6A
Maximum Pulsed Switch Current, Pulse < 3	300µs, 2% Duty
Cycle	8A
Package Thermal Resistance	
TDFN-3×3-8EL, $\theta_{JA}$	36.9°C/W
TDFN-3×3-8EL, $\theta_{JB}$	3.3°C/W
TDFN-3×3-8EL, $\theta_{JC (TOP)}$	44.1°C/W
TDFN-3×3-8EL, $\theta_{JC (BOT)}$	1.5°C/W
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
HBM	2000V
CDM	1000V

#### RECOMMENDED OPERATING CONDITIONS

$0.6V \text{ to } V_{\text{BIAS}} - 1.95V$
3V to 5.5V
0V to 5.5V
V <sub>IN</sub>
> 1µF
1.2V to 5.5V
0V to 0.5V
40°C to +125°C
40°C to +85°C

#### OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

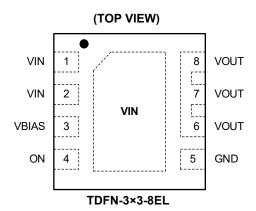
#### **ESD SENSITIVITY CAUTION**

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

#### DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

# **PIN CONFIGURATION**



# **PIN DESCRIPTION**

PIN	NAME	FUNCTION
1, 2	VIN	Switch Input Pins. Use a bypass capacitor $(C_{\text{IN}})$ as close as possible between this pin and GND pin.
3	VBIAS	Power Supply Pin for Internal Circuitry. V <sub>BIAS</sub> voltage range is from 3V to 5.5V.
4	ON	Switch Enable Input. Logic high sets the device active, logic low disables it and turns it into shutdown mode. Do not leave this pin floating.
5	GND	Ground.
6, 7, 8	VOUT	Switch Output Pins. Use a bypass capacitor (C <sub>OUT</sub> ) between this pin and GND pin.
Exposed Pad	VIN	Switch Input Pin. A bypass capacitor between exposed pad and GND pin is recommended.

## **ELECTRICAL CHARACTERISTICS**

( $V_{BIAS}$  = 5V, typical values are at  $T_A$  = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
Power Supplies and Currents (V <sub>BIA</sub>	s = 5V)						
VBIAS Quiescent Current	I <sub>Q_BIAS</sub>	$I_{OUT} = 0A$ , $V_{IN} = 3V$ , $V_{ON} = V_{BIAS} = 5V$ , $T_A = -40$ °C to +85°C		0.6	1	μA	
VBIAS Shutdown Current	I <sub>SD_BIAS</sub>	$V_{ON} = 0V$ , $V_{OUT} = 0V$ , $T_A = -40$ °C to +85°C			0.1	μA	
		$V_{ON} = 0V, V_{OUT} = 0V, V_{IN} = 3V, T_A = +25^{\circ}C$		0.0009	0.1		
		$V_{ON} = 0V$ , $V_{OUT} = 0V$ , $V_{IN} = 2.5V$ , $T_A = +25$ °C		0.0008	0.1		
VIN Shutdown Current	I <sub>SD_VIN</sub>	$V_{ON} = 0V$ , $V_{OUT} = 0V$ , $V_{IN} = 2.0V$ , $T_A = +25$ °C		0.0007	0.1	μΑ	
		$V_{ON} = 0V$ , $V_{OUT} = 0V$ , $V_{IN} = 1.05V$ , $T_A = +25$ °C		0.0007	0.1		
		$V_{ON} = 0V$ , $V_{OUT} = 0V$ , $V_{IN} = 0.8V$ , $T_A = +25$ °C		0.0006	0.1		
ON Terminal Input Leakage Current	I <sub>ON</sub>	$V_{ON} = 5.5V$ , $T_A = -40^{\circ}C$ to $+85^{\circ}C$			0.1	μΑ	
Resistance Characteristics (V <sub>BIAS</sub> =	5V)						
		I <sub>OUT</sub> = -200mA, V <sub>IN</sub> = 3V, T <sub>A</sub> = +25°C		6.5	8		
	R <sub>on</sub>	I <sub>OUT</sub> = -200mA, V <sub>IN</sub> = 2.5V, T <sub>A</sub> = +25°C		5.3	6.3	mΩ	
On-Resistance		I <sub>OUT</sub> = -200mA, V <sub>IN</sub> = 2V, T <sub>A</sub> = +25°C		4.8	5.8		
		I <sub>OUT</sub> = -200mA, V <sub>IN</sub> = 1.05V, T <sub>A</sub> = +25°C		4.4	5.3	-	
		I <sub>OUT</sub> = -200mA, V <sub>IN</sub> = 0.8V, T <sub>A</sub> = +25°C		4.3	5.3		
Output Pull-Down Resistance	R <sub>PD</sub>	$V_{IN} = 5V$ , $V_{ON} = 0V$ , $V_{OUT} = 1V$ , $T_A = -40$ °C to +85°C		260	300	Ω	
Power Supplies and Currents (V <sub>BIA</sub>	s = 3V)						
VBIAS Quiescent Current	I <sub>Q_BIAS</sub>	$I_{OUT} = 0A$ , $V_{IN} = 1V$ , $V_{ON} = V_{BIAS} = 3V$ , $T_A = -40$ °C to +85°C		0.3	1	μA	
VBIAS Shutdown Current	I <sub>SD_BIAS</sub>	V <sub>ON</sub> = 0V, V <sub>OUT</sub> = 0V, T <sub>A</sub> = -40°C to +85°C			0.1	μA	
VIN Shutdown Current		$V_{ON} = 0V$ , $V_{OUT} = 0V$ , $V_{IN} = 1.05V$ , $T_A = +25$ °C	0.001 0.4		0.1		
VIII SHUUOWII CUITEIII	I <sub>SD_VIN</sub>	$V_{ON} = 0V$ , $V_{OUT} = 0V$ , $V_{IN} = 0.8V$ , $T_A = +25$ °C		0.0008	0.1	μA	
ON Terminal Input Leakage Current	I <sub>ON</sub>	V <sub>ON</sub> = 5.5V, T <sub>A</sub> = -40°C to +85°C			0.1	μA	
Resistance Characteristics (V <sub>BIAS</sub> =	3V)						
On-Resistance	В	I <sub>OUT</sub> = -200mA, V <sub>IN</sub> = 1.05V, T <sub>A</sub> = +25°C		6.7	8.4	mΩ	
OH-IVESISIAIICE	Ron	$I_{OUT} = -200 \text{mA}, V_{IN} = 0.8 \text{V}, T_A = +25 ^{\circ}\text{C}$ 5.8		7.0	mΩ		
Output Pull-Down Resistance	R <sub>PD</sub>	$V_{IN} = 3V$ , $V_{ON} = 0V$ , $V_{OUT} = 1V$ , $T_A = -40$ °C to +85°C		260	300	Ω	

# **SWITCHING CHARACTERISTICS**

 $(T_A = +25$ °C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
V <sub>IN</sub> = 2.5V, V <sub>ON</sub> = V <sub>BIAS</sub> = 5V	•					
Turn-On Time	t <sub>ON</sub>			10.6		
Turn-Off Time	t <sub>OFF</sub>			4.9		
V <sub>OUT</sub> Rise Time	t <sub>R</sub>	R <sub>OUT</sub> = 10Ω, C <sub>OUT</sub> = 0.1μF		8.1		μs
V <sub>OUT</sub> Fall Time	t <sub>F</sub>			2.1		
Delay Time	t <sub>D</sub>			8.3		
V <sub>IN</sub> = 1.05V, V <sub>ON</sub> = V <sub>BIAS</sub> = 5V						
Turn-On Time	t <sub>ON</sub>		7.49	10.70	16.05	
Turn-Off Time	t <sub>OFF</sub>	L = 2.2μH (DCR = 0.33Ω), C <sub>OUT</sub> = 2 × 22μF (Refer to Typical Application Powering Rails		8000		
V <sub>OUT</sub> Rise Time	t <sub>R</sub>	Sensitive to Ringing and Over-Voltage due to Fast	1.6	4.2	7.0	μs
V <sub>OUT</sub> Fall Time	t <sub>F</sub>	Rise Time)		28100		
Delay Time	t <sub>D</sub>		5.95	8.50	11.05	
$V_{IN} = 0.8V$ , $V_{ON} = V_{BIAS} = 5V$						
Turn-On Time	ton			10		
Turn-Off Time	t <sub>OFF</sub>			5.6		
V <sub>OUT</sub> Rise Time	t <sub>R</sub>	$R_{OUT} = 10\Omega, C_{OUT} = 0.1\mu F$		2.8		μs
V <sub>OUT</sub> Fall Time	t <sub>F</sub>			2.0		
Delay Time	t <sub>D</sub>			8.7		
$V_{IN} = 1.05V, V_{ON} = 5V, V_{BIAS} = 3V$						
Turn-On Time	ton			22.6		
Turn-Off Time	t <sub>OFF</sub>			4.2		
V <sub>OUT</sub> Rise Time	t <sub>R</sub>	$R_{OUT} = 10\Omega, C_{OUT} = 0.1 \mu F$		11.6		μs
V <sub>OUT</sub> Fall Time	t <sub>F</sub>			2		
Delay Time	t <sub>D</sub>			18.4		
$V_{IN} = 0.8V, V_{ON} = 5V, V_{BIAS} = 3V$						
Turn-On Time	t <sub>ON</sub>			22.1		
Turn-Off Time	t <sub>OFF</sub>			4.4		
V <sub>OUT</sub> Rise Time	t <sub>R</sub>	$R_{OUT} = 10\Omega, C_{OUT} = 0.1\mu F$		7.8		μs
V <sub>OUT</sub> Fall Time	t <sub>F</sub>			2		
Delay Time	t <sub>D</sub>			18.6		

## PARAMETER MEASUREMENT INFORMATION

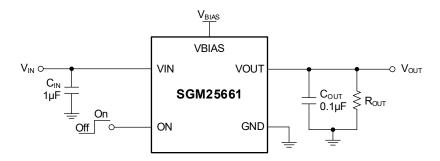


Figure 2. Test Circuit 1

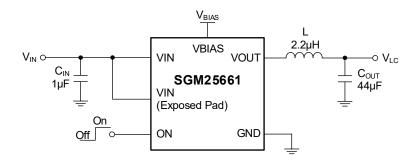


Figure 3. Test Circuit 2

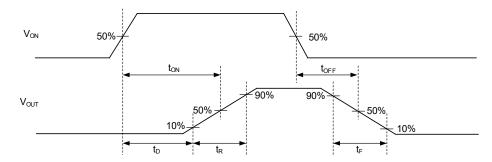
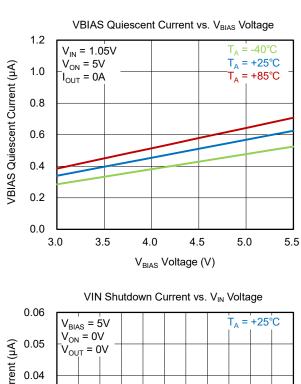
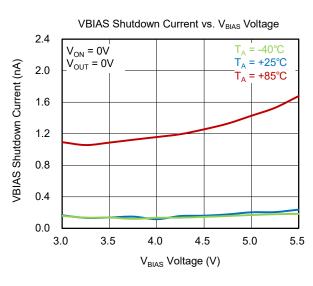
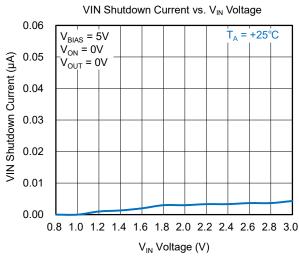


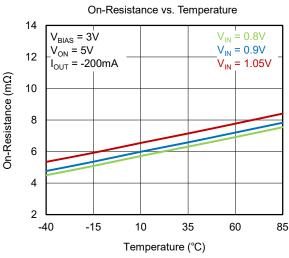
Figure 4. Timing Waveforms

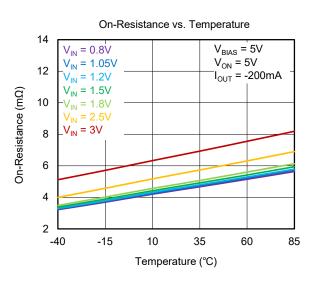
## TYPICAL PERFORMANCE CHARACTERISTICS

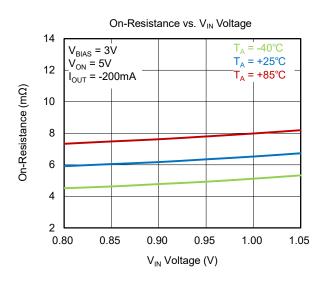


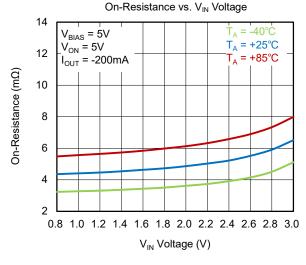


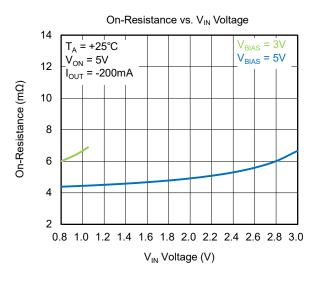


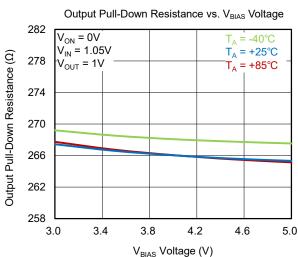


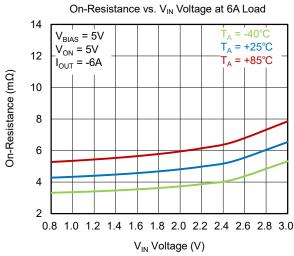


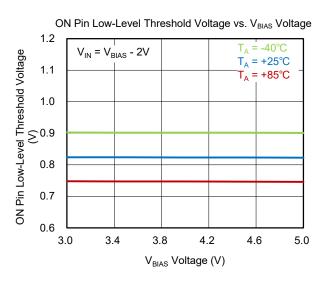


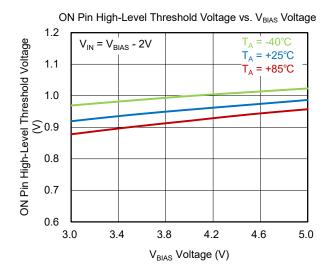


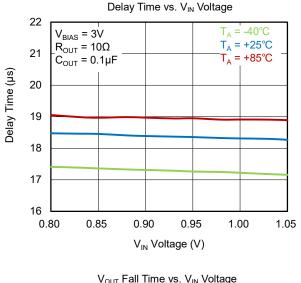


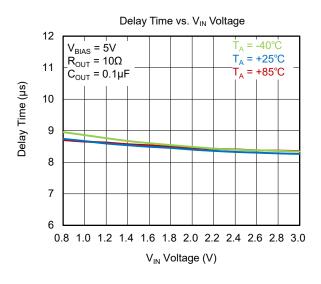


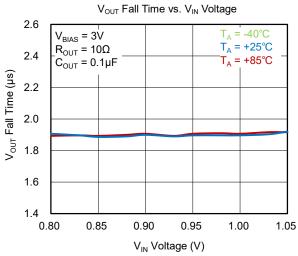


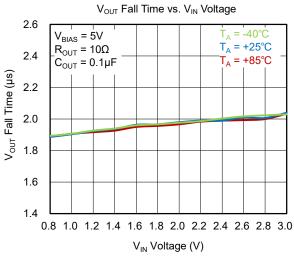


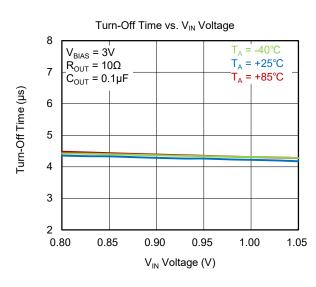


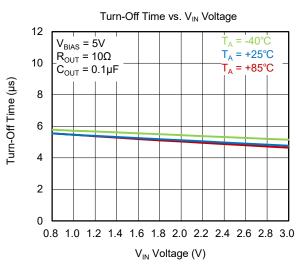


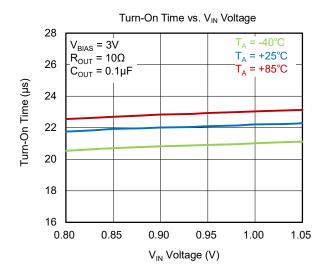


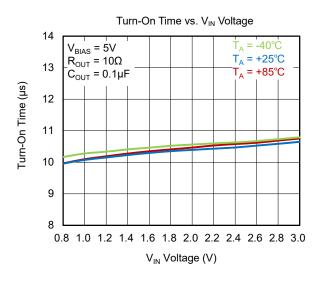


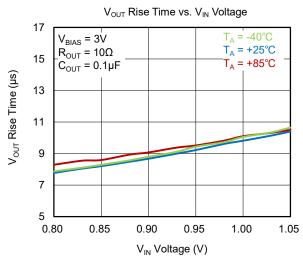


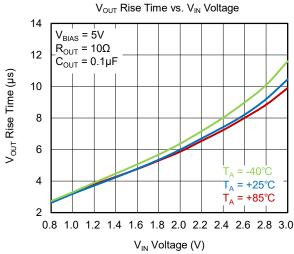


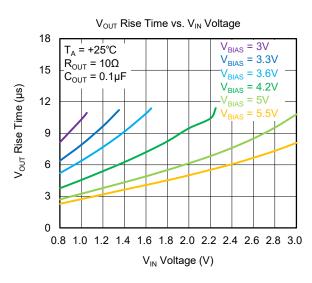


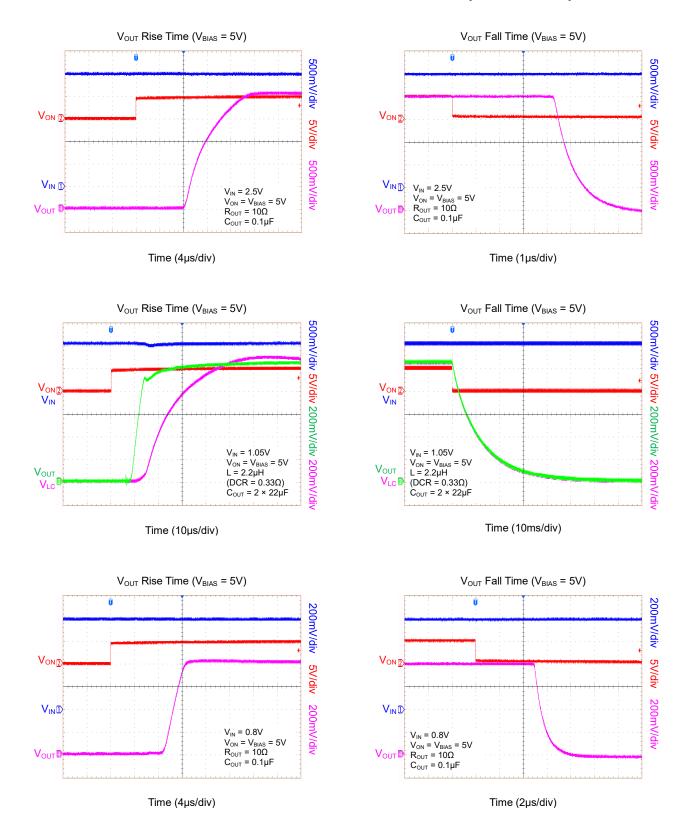


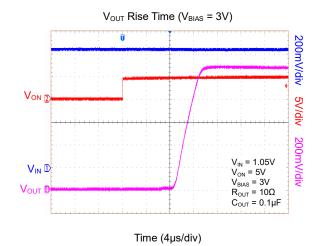


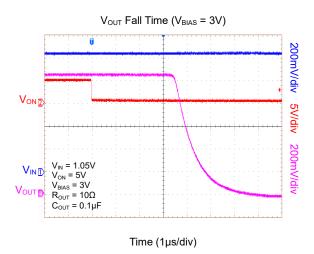


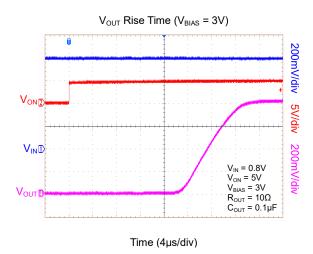


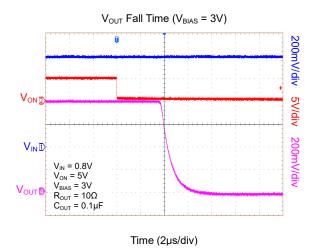












# **FUNCTIONAL BLOCK DIAGRAM**

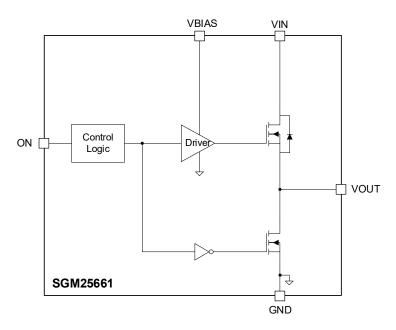


Figure 5. Block Diagram

#### **DETAILED DESCRIPTION**

#### Overview

The SGM25661 is a 3.5V,  $5.3m\Omega$  (TYP) on-resistance, integrated N-MOSFET, single channel load switch. It can support a 6A maximum continuous load current and be enabled by the ON pin. The device has a fixed slew rate (or the soft-start time) of  $V_{\text{OUT}}$ , which can control the inrush current and reduce the voltage drop. The SGM25661 includes internal integrated fast output discharge to remove the remaining charge from the output when the switch is disabled. Once the device is turned off, the leakage current will be very low, thus reducing unnecessary leakage of the downstream modules.

SGM25661 is highly integrated. Using SGM25661 can reduce the PCB area and the BOM count greatly, even the cost.

#### On/Off Control

There is a control pin ON to turn on or turn off the corresponding N-MOSFET. When the ON pin is driven high, the switch will be turned on, and when the ON pin is driven low, the switch will be turned off. The ON pin is suitable for standard GPIO logic level threshold, such as 1.2V, 1.8V, 2.5V or 3.3V. The ON pin cannot be left floating and must be connected to either high or low level as requirement.

#### Input Capacitor (C<sub>IN</sub>)

Turning on the N-MOSFET to charge load capacitor will generate inrush current, which may cause the  $V_{\text{IN}}$  drop. In order to prevent the drop, a capacitor must be placed between the VIN and GND pins. Usually, a  $1\mu\text{F}$  input capacitor ( $C_{\text{IN}}$ ) placed close to the pins is sufficient. However, higher capacitance values could reduce the voltage drop. So, larger  $C_{\text{IN}}$  can be used to reduce the voltage drop in high current applications.

## **Output Capacitor (Cout)**

A 0.1 $\mu$ F output capacitor ( $C_{OUT}$ ) should be placed between the VOUT and GND pins. This capacitor can prevent parasitic board inductance from forcing  $V_{OUT}$  below GND when the switch is turned on. It is recommended that  $C_{IN}$  should be greater than  $C_{OUT}$ .

#### V<sub>IN</sub> and V<sub>BIAS</sub> Voltage Range

It is recommended that  $V_{BIAS}$  is greater than ( $V_{OUT}$  + 1.95V), otherwise  $R_{ON}$  will be much larger than the rated value in the electrical characteristics ( $V_{BIAS}$  = 5V table). The device can still be functional if the  $V_{BIAS}$  is less than ( $V_{OUT}$  + 1.95V), but the increase of  $R_{ON}$  may cause the device in an undesirable condition.

In addition, the maximum rated voltage of VIN and VBIAS pins should not be exceeded when  $V_{\text{BIAS}}$  is greater than ( $V_{\text{OUT}}$  + 1.95V).

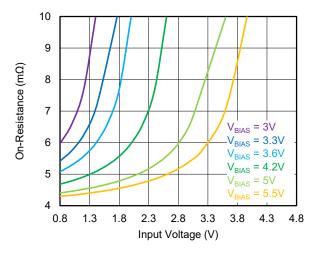


Figure 6. On-Resistance vs. Input Voltage

#### APPLICATION INFORMATION

### **Typical Application Circuit**

Figure 7 shows the typical application circuit of SGM25661 as a load switch to power downstream equipment.

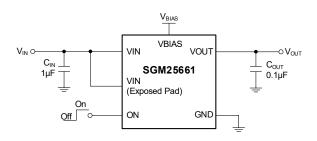


Figure 7. Typical Application Schematic

#### **Design Requirements**

In the design example of this part, the specific design parameters are shown in the following table.

**Table 1. Design Parameters** 

Design Parameter	Example Value
V <sub>IN</sub>	1.05V
V <sub>BIAS</sub>	5.0V
Load Current	6A

#### **Detailed Design Procedure**

First, the following three parameters need to be determined by the designer:  $V_{\text{IN}}$  voltage,  $V_{\text{BIAS}}$  voltage and load current.

#### VIN to VOUT Voltage Drop

The voltage drop between input and output is determined by  $R_{ON}$  and load current.  $R_{ON}$  is determined by the specific  $V_{IN}$  and  $V_{BIAS}$  voltage. Therefore, after the above two parameters are determined, the voltage drop between input and output can be calculated by Equation 1:

$$\triangle V = I_{LOAD} \times R_{ON} \tag{1}$$

where  ${}^{\triangle}V$  is the voltage drop from input to output.  $I_{LOAD}$  is the load current.  $R_{ON}$  is the on-resistance of device determined by  $V_{IN}$  and  $V_{BIAS}$ .

Note that the chosen load current should not exceed the maximum rated value of the load current (6A for the SGM25661).

#### **Inrush Current**

The specific value of inrush current caused by output capacitance  $C_{\text{OUT}}$  can be calculated by Equation 2:

$$I_{INRUSH} = C_{OUT} \times \frac{dV_{OUT}}{dt}$$
 (2)

where  $I_{\text{INRUSH}}$  is the value of inrush current caused by  $C_{\text{OUT}}$ .  $C_{\text{OUT}}$  is the output capacitance value.  $dV_{\text{OUT}}$  is the rising change value of  $V_{\text{OUT}}$  after the device is enabled. dt is the time taken by the device to increase  $V_{\text{OUT}}$  after the device is enabled.

Note that appropriate  $C_{\text{OUT}}$  will be chosen to prevent excessive inrush current and exceeding the maximum current rating.

#### **Thermal Considerations**

In order to avoid the maximum junction temperature of the device exceeding +125°C under normal operation, the maximum power dispersion of the device can be calculated by Equation 3 when the ambient temperature and load current are given.

$$P_{D(MAX)} = \frac{T_{J(MAX)} - T_A}{R_{\theta JA}}$$
 (3)

where  $P_{D(MAX)}$  is the maximum power dispersion of the device.  $T_{J(MAX)}$  is the maximum junction temperature of the device (+125°C for the SGM25661).  $T_A$  is the ambient temperature.  $\theta_{JA}$  is the junction to air thermal impedance which is highly dependent on layout of the board.

## **APPLICATION INFORMATION (continued)**

## **Another Type of Application**

Figure 8 shows the application circuit of SGM25661 on the power rail sensitive to ringing and over-voltage caused by fast rising time.

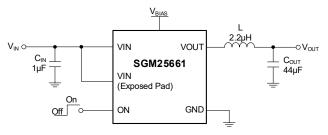


Figure 8. Typical Application Schematic for Powering Rails Sensitive to Ringing

#### **Design Requirements**

In the design example of this part, the specific design parameters are shown in the following table.

**Table 2. Design Parameters** 

Design Parameter	Example Value
V <sub>IN</sub>	1.05V
$V_{BIAS}$	5.0V
Acceptable Percent Overshoot (ρ)	3.2%
Maximum Settling Time (t <sub>SETTLE</sub> )	40µs

#### **Detailed Design Procedure**

First, the following four parameters need to be determined by the designer:  $V_{\text{IN}}$  voltage,  $V_{\text{BIAS}}$  voltage, acceptable percent overshoot and maximum allowed settling time for the power rail.

#### Selecting Proper Inductor and Capacitor to Meet Voltage Overshoot Requirements

In order to determine the specific parameters of L and  $C_{\text{OUT}}$  in the filter circuit, the damping factor determined by the acceptable percent overshoot needs to be calculated by the predecessors. The calculation formula is shown in Equation 4:

$$\varepsilon = \frac{-\ln \rho}{\sqrt{\pi^2 + (\ln \rho)^2}} \tag{4}$$

where  $\epsilon$  is the damping factor of the filter.  $\rho$  is the acceptable percent overshoot.

Inductance (L), its DCR ( $R_{DCR}$ ) and capacitance ( $C_{OUT}$ ) will affect the damping factor calculated by Equation 4. The specific relationship is shown in Equation 5. Therefore, L and  $C_{OUT}$  can determine an optimal parameter combination through multiple iterations. The

calculation of filter setting time (< 5% of the steady state value) is shown in Equation 6.

$$\varepsilon = \frac{R_{DCR}}{2} \times \sqrt{\frac{C_{OUT}}{I}}$$
 (5)

$$t_{\text{SETTLE}} \approx \frac{3 \times \sqrt{L \times C_{\text{OUT}}}}{\epsilon}$$
 (6)

where  $\epsilon$  is the damping factor of the filter.  $R_{DCR}$  is the DCR of inductor.  $C_{OUT}$  is the capacitance of the LC filter. L is the inductance of the LC filter.  $t_{SETTLE}$  is the setting time of the LC filter (< 5% of the steady state value).

The damping factor and filter setting time requirements in Table 2 will constrain the parameter selection of L,  $R_{DCR}$  and  $C_{OUT}$ .

#### Power Supply Recommendations

The voltage range of  $V_{\text{IN}}$  and  $V_{\text{BIAS}}$  in the device is 0.6V to 3.5V and 3V to 5.5V respectively. The power supply voltage should be well regulated and close to SGM25661. If the power supply is more than a few inches from the pin of the device, the additional bulk capacitor needs to be connected in parallel to the ceramic bypass capacitor. An electrolytic, tantalum, or  $10\mu\text{F}$  ceramic capacitor may be sufficient.

#### **Layout Guidelines**

- The main power traces should be as short and wide as possible to accommodate for high current.
- The vias should be used under the exposed pad for better heat dissipation under high current conditions.
- The VIN pin requires a ceramic capacitor with low ESR in parallel for bypass. The recommended bypass capacitor is 1µF ceramic with X5R or X7R dielectric. The bypass capacitor should be placed next to the device pin as close as possible.
- The VOUT pin requires a ceramic capacitor with low ESR in parallel for bypass. The VIN bypass capacitor with X5R or X7R dielectric should be ten times larger than the VOUT bypass capacitor. The bypass capacitor should be placed next to the device pin as close as possible.
- The V<sub>BIAS</sub> pin requires a ceramic capacitor with low ESR in parallel for bypass. The recommended bypass capacitor is 0.1µF with X5R or X7R dielectric.

# SGM25661

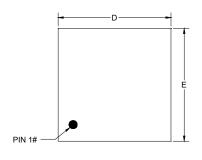
## **REVISION HISTORY**

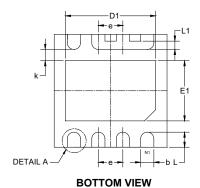
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

MAY 2025 – REV.A to REV.A.1	Page
Updated Input Voltage Range	1, 16
Updated Absolute Maximum Ratings section	2
Updated Typical Application Circuit	All
Changes from Original (DECEMBER 2022) to REV.A	Page
Changed from product preview to production data	All

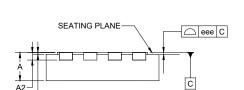


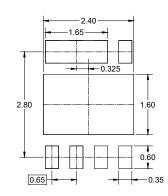
# PACKAGE OUTLINE DIMENSIONS TDFN-3×3-8EL











#### SIDE VIEW



RECOMMENDED LAND PATTERN (Unit: mm)

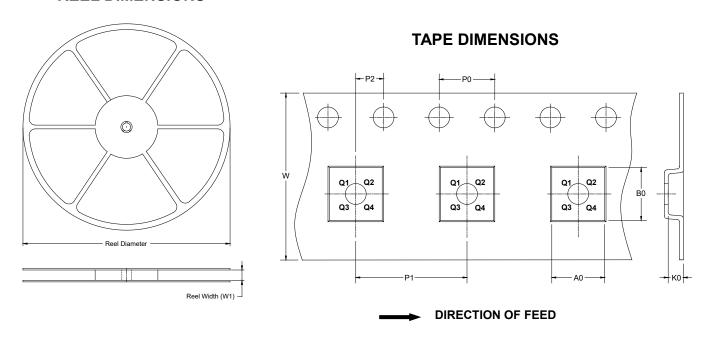
Cumbal	Dimensions In Millimeters					
Symbol	MIN	NOM	MAX			
А	0.700	-	0.800			
A1	0.000	-	0.050			
A2		0.200 REF				
b	0.300	-	0.400			
D	2.900	-	3.100			
Е	2.900	-	3.100			
D1	2.300	-	2.500			
E1	1.500	-	1.700			
е						
L	0.300	-	0.500			
L1	0.120	-	0.320			
k	0.300 REF					
eee	0.080					

NOTE: This drawing is subject to change without notice.



## TAPE AND REEL INFORMATION

#### **REEL DIMENSIONS**

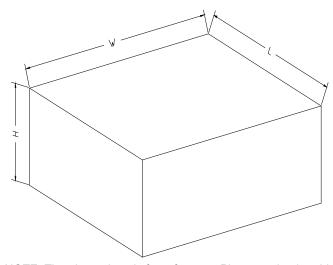


NOTE: The picture is only for reference. Please make the object as the standard.

#### **KEY PARAMETER LIST OF TAPE AND REEL**

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
TDFN-3×3-8EL	13″	12.4	3.30	3.30	1.10	4.0	8.0	2.0	12.0	Q2

## **CARTON BOX DIMENSIONS**



NOTE: The picture is only for reference. Please make the object as the standard.

#### **KEY PARAMETER LIST OF CARTON BOX**

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
13"	386	280	370	5